

**April 2009** 

# FOD2742A, FOD2742B, FOD2742C Optically Isolated Error Amplifier

#### **Features**

- Optocoupler, precision reference and error amplifier in single package
- 2.5V reference
- CTR 100% to 200%
- 2,500V RMS isolation
- UL approval E90700, Volume 2
- BSI approval 8661, 8662
- VDE approval 136616
- CSA approval 1113643
- Low temperature coefficient 50 ppm/°C max.
- FOD2742A: tolerance 0.5% FOD2742B: tolerance 1% FOD2742C: tolerance 2%

## **Applications**

- Power supplies regulation
- DC to DC converters

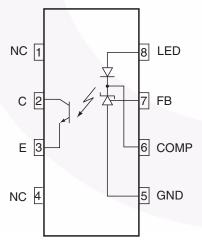
## Description

The FOD2742 Optically Isolated Amplifier consists of the popular KA431 precision programmable shunt reference and an optocoupler. The optocoupler is a gallium arsenide (GaAs) light emitting diode optically coupled to a silicon phototransistor. It comes in 3 grades of reference voltage tolerance = 2%, 1%, and 0.5%.

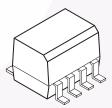
The Current Transfer Ratio (CTR) ranges from 100% to 200%. It also has an outstanding temperature coefficient of 50 ppm/°C. It is primarily intended for use as the error amplifier/reference voltage/optocoupler function in isolated ac to dc power supplies and dc/dc converters.

When using the FOD2742, power supply designers can reduce the component count and save space in tightly packaged designs. The tight tolerance reference eliminates the need for adjustments in many applications. The device comes in a 8-pin small outline package.

### **Schematic**



# Package Outline

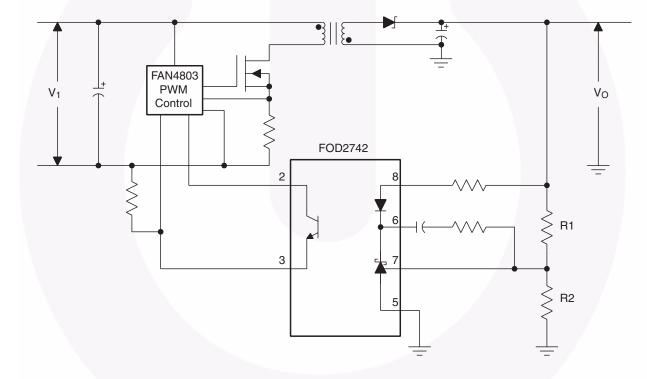


## **Pin Definitions**

Pin Number	Pin Name	Functional Description
1	NC	Not connected
2	С	Phototransistor Collector
3	E	Phototransistor Emitter
4	NC	Not connected
5	GND	Ground
6	COMP	Error Amplifier Compensation. This pin is the output of the error amplifier.*
7	FB	Voltage Feedback. This pin is the inverting input to the error amplifier
8	LED	Anode LED. This pin is the input to the light emitting diode.

<sup>\*</sup>The compensation network must be attached between pins 6 and 7.

# **Typical Application**



## **Absolute Maximum Ratings** (T<sub>A</sub> = 25°C unless otherwise specified)

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Value	Units
T <sub>STG</sub>	Storage Temperature	-40 to +125	°C
T <sub>OPR</sub>	Operating Temperature	-25 to +85	°C
	Reflow Temperature Profile (refer to 15)		
V <sub>LED</sub>	Input Voltage	37	V
I <sub>LED</sub>	Input DC Current	20	mA
V <sub>CEO</sub>	Collector-Emitter Voltage	70	V
V <sub>ECO</sub>	Emitter-Collector Voltage	7	V
I <sub>C</sub>	Collector Current	50	mA
PD1	Input Power Dissipation <sup>(1)</sup>	145	mW
PD2	Transistor Power Dissipation <sup>(2)</sup>	85	mW
PD3	Total Power Dissipation <sup>(3)</sup>	145	mW

#### Notes:

- 1. Derate linearly from 25°C at a rate of 2.42mW/°C
- 2. Derate linearly from 25°C at a rate of 1.42mW/°C.
- 3. Derate linearly from 25°C at a rate of 2.42mW/°C.

# **Electrical Characteristics** (T<sub>A</sub> = 25°C unless otherwise specified)

## **Input Characteristics**

Symbol	Parameter	Tes	t Conditions	Device	Min.	Тур.	Max.	Unit									
V <sub>F</sub>	LED Forward Voltage	I <sub>LED</sub> = 10mA,	V <sub>COMP</sub> = V <sub>FB</sub> (Fig. 1)	All		1.20	1.5	V									
V <sub>REF</sub>	Reference Voltage	$I_{LED} = 10 \text{mA},$	V <sub>COMP</sub> = V <sub>FB</sub> (Fig. 1)	А	2.482	2.495	2.508	V									
				В	2.470	2.495	2.520	V									
				С	2.450	2.500	2.550	V									
V <sub>REF (DEV)</sub>	Deviation of V <sub>REF</sub> Over Temperature	$T_A = -25^{\circ}C$ to	+85°C (Fig. 1)	All		3.5	17	mV									
$\Delta V_{RE}$	Ratio of V <sub>REF</sub> Variation to	I <sub>LED</sub> = 10mA	$\Delta V_{COMP} = 10V \text{ to } V_{REF}$	All		-0.5	-2.7	mV/									
$\Delta V_{COMP}$	the Output of the Error Amplifier	(Fig. 2)	(Fig. 2)	(Fig. 2)	(Fig. 2)	(Fig. 2)	(Fig. 2)	(Fig. 2)	(Fig. 2)	(Fig. 2)	(Fig. 2)	(Fig. 2) $\Delta V_{COMP} = 36V \text{ to } 10V$			-0.3	-2.0	V
I <sub>REF</sub>	Feedback Input Current	I <sub>LED</sub> = 10mA,	$I_{LED}$ = 10mA, $R_1$ = 10KΩ (Fig. 3)			2.2	4	μA									
I <sub>REF (DEV)</sub>	Deviation of I <sub>REF</sub> Over Temperature	$T_A = -25^{\circ}C$ to	$T_A = -25^{\circ}C \text{ to } +85^{\circ}C \text{ (Fig. 3)}$			1.0	1.2	μA									
I <sub>LED (MIN)</sub>	Minimum Drive Current	$V_{COMP} = V_{FB}$	V <sub>COMP</sub> = V <sub>FB</sub> (Fig. 1)			0.45	1.0	mA									
I <sub>(OFF)</sub>	Off-state Error Amplifier Current	$V_{LED} = 37V, V_{FB} = 0 \text{ (Fig. 4)}$		All		0.01	1.0	μA									
IZ <sub>OUT</sub> I	Error Amplifier Output Impedance (see note 2)	V <sub>COMP</sub> = V <sub>REF</sub> f ≥ 1.0kHz	$I_{LED} = 1$ mA to 20mA,	All		0.15	0.5	Ω									

#### Notes:

 The deviation parameters V<sub>REF(DEV)</sub> and I<sub>REF(DEV)</sub> are defined as the differences between the maximum and minimum values obtained over the rated temperature range. The average full-range temperature coefficient of the reference input voltage, ΔV<sub>REF</sub>, is defined as:

$$\left|\Delta V_{REF}\right|(ppm/^{\circ}C) \; = \; \frac{\{V_{REF(DEV)}/V_{REF}(T_{A}=25^{\circ}C)\} \times 10^{6}}{\Delta T_{A}}$$

where  $\Delta T_{\mbox{\scriptsize A}}$  is the rated operating free-air temperature range of the device.

2. The dynamic impedance is defined as  $|Z_{OUT}| = \Delta V_{COMP}/\Delta I_{LED}$ . When the device is operating with two external resistors (see Figure 2), the total dynamic impedance of the circuit is given by:

$$\left|Z_{OUT,\;TOT}\right| = \frac{\Delta V}{\Delta I} \approx \left|Z_{OUT}\right| \times \left[1 + \frac{R1}{R2}\right]$$

# **Electrical Characteristics** ( $T_A = 25$ °C unless otherwise specified) (Continued)

### **Output Characteristics**

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
I <sub>CEO</sub>	Collector Dark Current	V <sub>CE</sub> = 10V (Fig. 5)		1	50	nA
BV <sub>ECO</sub>	Emitter-Collector Voltage Breakdown	I <sub>E</sub> = 100μA	7	10		V
BV <sub>CEO</sub>	Collector-Emitter Voltage Breakdown	I <sub>C</sub> = 1.0mA	70	120		V

#### **Transfer Characteristics**

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
CTR	Current Transfer Ratio	$I_{LED} = 10\text{mA}, V_{COMP} = V_{FB},$ $V_{CE} = 5V \text{ (Fig. 6)}$	100	140	200	%
V <sub>CE (SAT)</sub>	Collector-Emitter Saturation Voltage	$I_{LED}$ = 10mA, $V_{COMP}$ = $V_{FB}$ , $I_{C}$ = 2.5mA (Fig. 6)		0.16	0.4	٧

#### **Isolation Characteristics**

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
I <sub>I-O</sub>	Input-Output Insulation Leakage Current	RH = 45%, T <sub>A</sub> = 25°C, t = 5s, V <sub>I-O</sub> = 3000 VDC (Note 1)			1.0	μΑ
V <sub>ISO</sub>	Withstand Insulation Voltage	$RH \le 50\%$ , $T_A = 25$ °C, $t = 1$ min. (Note 1)	2500			Vrms
R <sub>I-O</sub>	Resistance (Input to Output)	V <sub>I-O</sub> = 500 VDC (Note 1)		10 <sup>12</sup>		Ω

### **Switching Characteristics**

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
B <sub>W</sub>	Bandwidth	Fig. 7		50		kHz
CMH	Common Mode Transient Immunity at Output HIGH	$I_{LED} = 0 \text{mA},  V_{cm}  = 10 V_{PP}$ RL = 2.2k $\Omega$ (Fig. 8) (Note 2)		1.0		kV/μs
CML	Common Mode Transient Immunity at Output LOW	$I_{LED} = 10 \text{mA},  V_{cm}  = 10 V_{PP}$ RL = 2.2k $\Omega$ (Fig. 8) (Note 2)		1.0		kV/μs

### Notes:

- 1. Device is considered as a two terminal device: Pins 1, 2, 3 and 4 are shorted together and Pins 5, 6, 7 and 8 are shorted together.
- 2. Common mode transient immunity at output high is the maximum tolerable (positive) dVcm/dt on the leading edge of the common mode impulse signal, Vcm, to assure that the output will remain high. Common mode transient immunity at output low is the maximum tolerable (negative) dVcm/dt on the trailing edge of the common pulse signal, Vcm, to assure that the output will remain low.

## **Test Circuits**

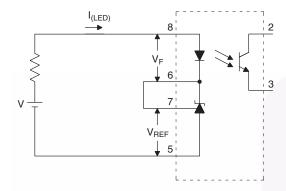


Figure 1. V<sub>REF</sub>, V<sub>F</sub>, I<sub>LED</sub> (min) Test Circuit

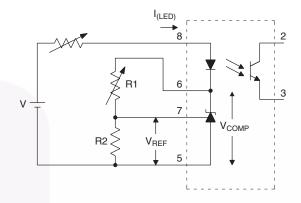


Figure 2.  $\Delta V_{REF}/\Delta V_{COMP}$  Test Circuit

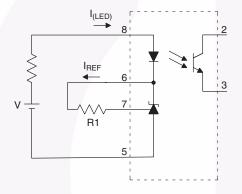


Figure 3. I<sub>REF</sub> Test Circuit

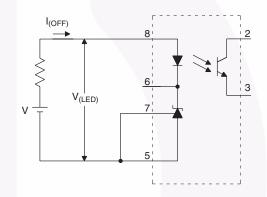


Figure 4. I<sub>(OFF)</sub> Test Circuit

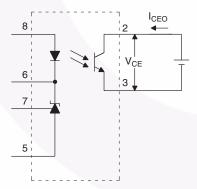


Figure 5. I<sub>CEO</sub> Test Circuit

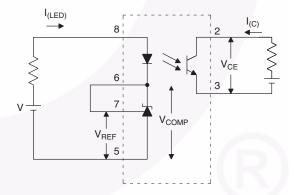


Figure 6. CTR, V<sub>CE(sat)</sub> Test Circuit

## Test Circuits (Continued)

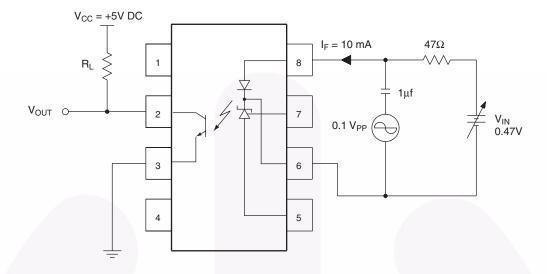


Figure 7. Frequency Response Test Circuit

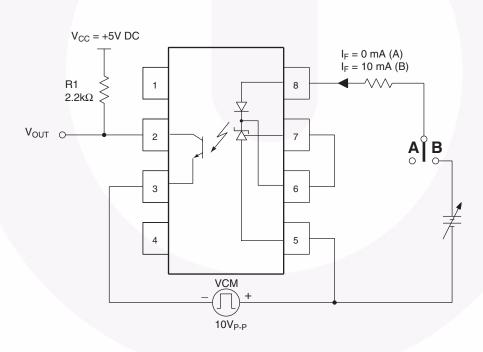
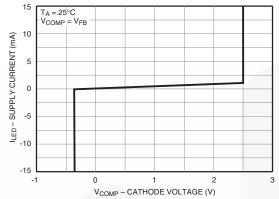


Figure 8. CMH and CML Test Circuit

## **Typical Performance Curves**

Fig. 9a LED Current vs. Cathode Voltage



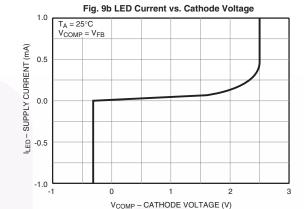
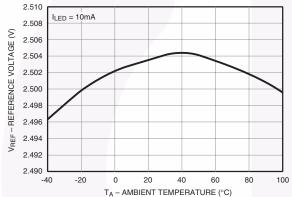


Fig. 10 Reference Voltage vs. Ambient Temperature



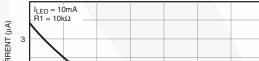


Fig. 11 Reference Current vs Ambient Temperature

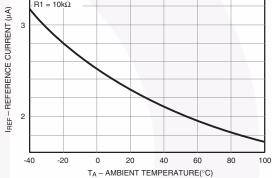
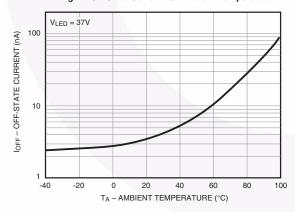
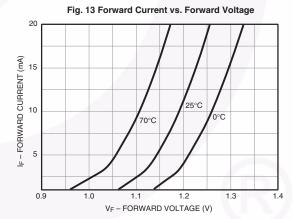


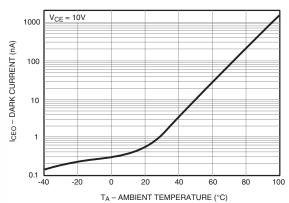
Fig. 12 Off-State Current vs. Ambient Temperature

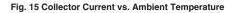




## Typical Performance Curves (Continued)

Fig. 14 Dark Current vs. Ambient Temperature





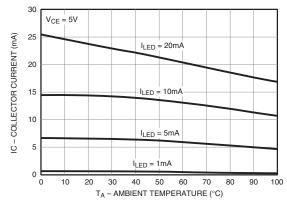


Fig. 16 Current Transfer Ratio vs. LED Current

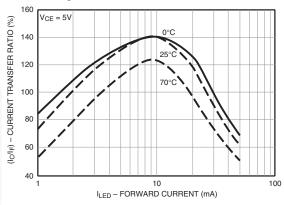


Fig. 17 Saturation Voltage vs. Ambient Temperature

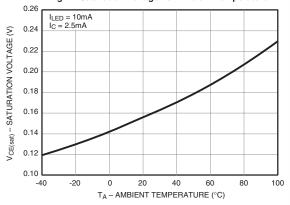


Fig. 18 Collector Current vs. Collector Voltage

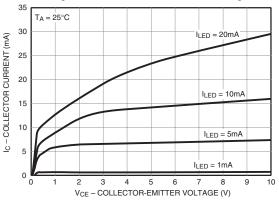
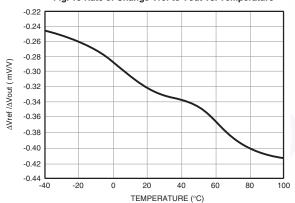
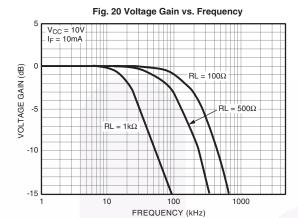


Fig. 19 Rate of Change Vref to Vout vs. Temperature



# **Typical Performance Curves** (Continued)



### The FOD2742

The FOD2742 is an optically isolated error amplifier. It incorporates three of the most common elements necessary to make an isolated power supply, a reference voltage, an error amplifier, and an optocoupler. It is functionally equivalent to the popular KA431 shunt voltage regulator plus the CNY17F-X optocoupler.

## **Powering the Secondary Side**

The LED pin in the FOD2742 powers the secondary side, and in particular provides the current to run the LED. The actual structure of the FOD2742 dictates the minimum voltage that can be applied to the LED pin: The error amplifier output has a minimum of the reference voltage, and the LED is in series with that. Minimum voltage applied to the LED pin is thus 2.5V + 1.5V = 4.0V. This voltage can be generated either directly from the output of the converter, or else from a slaved secondary winding. The secondary winding will not affect regulation, as the input to the FB pin may still be taken from the output winding.

The LED pin needs to be fed through a current limiting resistor. The value of the resistor sets the amount of current through the LED, and thus must be carefully selected in conjunction with the selection of the primary side resistor.

#### **Feedback**

Output voltage of a converter is determined by selecting a resistor divider from the regulated output to the FB pin. The FOD2742 attempts to regulate its FB pin to the reference voltage, 2.5V. The ratio of the two resistors should thus be:

$$\frac{R_{TOP}}{R_{BOTTOM}} = \frac{V_{OUT}}{V_{REF}} - 1$$

The absolute value of the top resistor is set by the input offset current of  $5.2\mu A$ . To achieve 0.5% accuracy, the resistance of  $R_{TOP}$  should be:

$$\frac{V_{OUT}-2.5}{R_{TOP}} > 1040 \mu A$$

## Compensation

The compensation pin of the FOD2742 provides the opportunity for the designer to design the frequency response of the converter. A compensation network may be placed between the COMP pin and the FB pin. In typical low-bandwidth systems, a 0.1µF capacitor may be used. For converters with more stringent requirements, a network should be designed based on measurements of the system's loop. An excellent reference for this process may be found in "Practical Design of Power Supplies" by Ron Lenk, IEEE Press, 1998.

## **Secondary Ground**

The GND pin should be connected to the secondary ground of the converter.

### **No Connect Pins**

The NC pins have no internal connection. They should not have any connection to the secondary side, as this may

compromise the isolation structure.

### **Photo-Transistor**

The Photo-transistor is the output of the FOD2742. In a normal configuration the collector will be attached to a pull-up resistor and the emitter grounded. There is no base connection necessary.

The value of the pull-up resistor, and the current limiting resistor feeding the LED, must be carefully selected to account for voltage range accepted by the PWM IC, and for the variation in current transfer ratio (CTR) of the opto-isolator itself.

**Example:** The voltage feeding the LED pins is +12V, the voltage feeding the collector pull-up is +10V, and the PWM IC is the Fairchild KA1H0680, which has a 5V reference. If we select a 10KV resistor for the LED, the maximum current the LED can see is:

$$(12V-4V)/10K\Omega = 800\mu A.$$

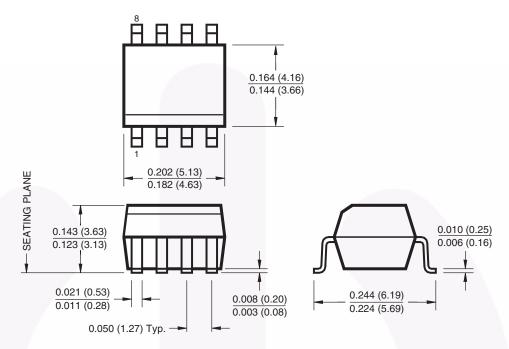
The CTR of the opto-isolator is a minimum of 100%, so the minimum collector current of the photo-transistor when the diode is full on is also  $800\mu A$ . The collector resistor must thus be such that:

$$\frac{10V-5V}{R_{COLLECTOR}} < 800 \mu A \text{ or } R_{COLLECTOR} > 6.25 K\Omega;$$

select  $12K\Omega$  to allow some margin.

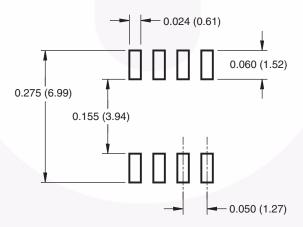
## **Package Dimensions**

## 8-pin SOIC Surface Mount



Lead Coplanarity: 0.004 (0.10) MAX

## **Recommended Pad Layout**



Dimensions in inches (mm).

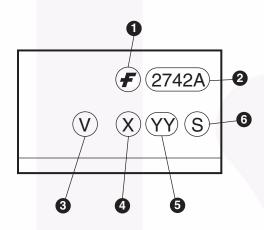
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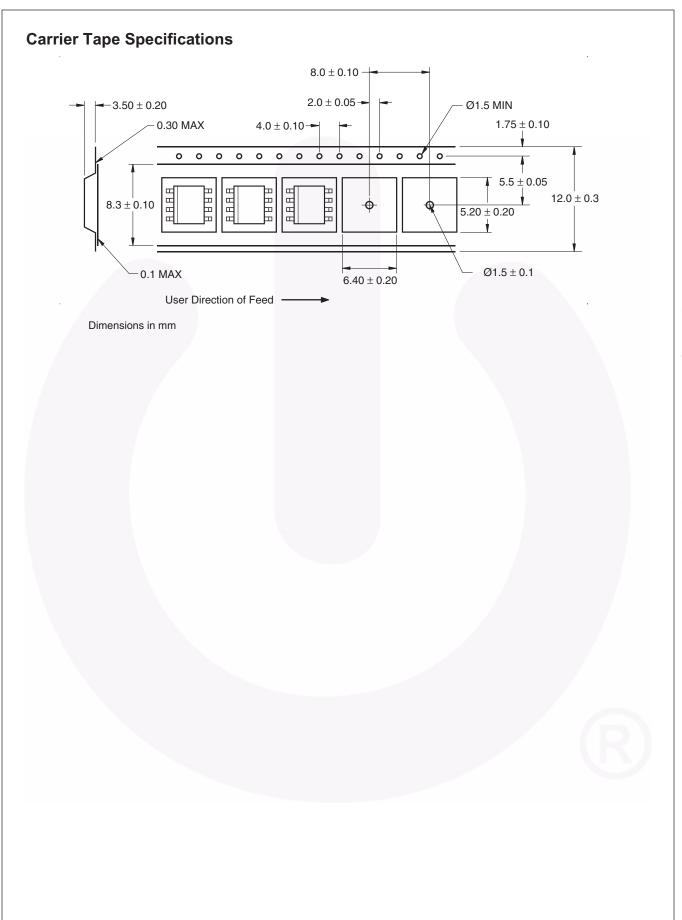
# **Ordering Information**

Option	Order Entry Identifier	Description
V	V	VDE 0884
R2	R2 Tape and reel (2500 units per reel)	
R2V	R2V VDE 0884, Tape and reel (2500 units per reel)	

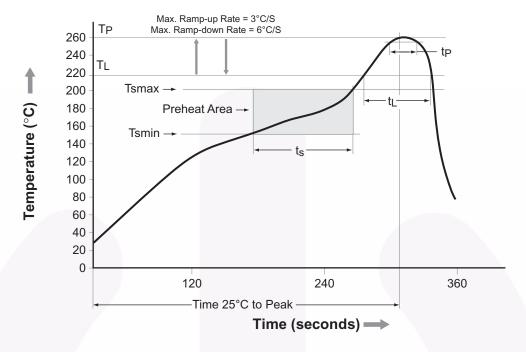
# **Marking Information**



Defini	itions
1	Fairchild logo
2	Device number
3	VDE mark (Note: Only appears on parts ordered with VDE option – See order entry table)
4	One digit year code, e.g., '3'
5	Two digit work week ranging from '01' to '53'
6	Assembly package code



## **Reflow Profile**



Profile Freature	Pb-Free Assembly Profile
Temperature Min. (Tsmin)	150°C
Temperature Max. (Tsmax)	200°C
Time (t <sub>S</sub> ) from (Tsmin to Tsmax)	60-120 seconds
Ramp-up Rate (t <sub>L</sub> to t <sub>P</sub> )	3°C/second max.
Liquidous Temperature (T <sub>L</sub> )	217°C
Time (t <sub>L</sub> ) Maintained Above (T <sub>L</sub> )	60-150 seconds
Peak Body Package Temperature	260°C +0°C / -5°C
Time (t <sub>P</sub> ) within 5°C of 260°C	30 seconds
Ramp-down Rate (T <sub>P</sub> to T <sub>L</sub> )	6°C/second max.
Time 25°C to Peak Temperature	8 minutes max.





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Deminition of Terms		
Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.

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